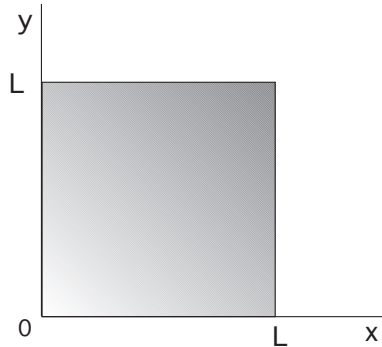


**Exam #1**

**Problem 1** (30 points) Quantum Dots

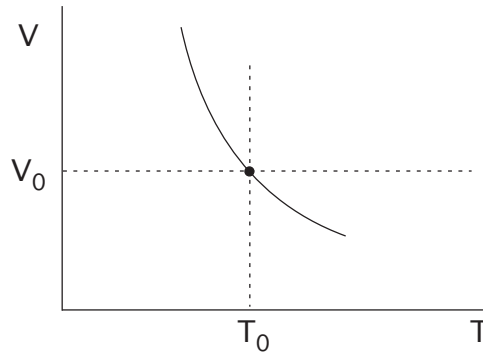


A complicated process creates quantum dots (also called artificial atoms) on the surface of a square chip of silicon. The probability density for finding a given dot at the location  $(x, y)$  on the chip is given by

$$\begin{aligned}
 p(x, y) &= \frac{1}{L^3} (x + y) && \text{when } 0 \leq x \leq L \text{ and } 0 \leq y \leq L \\
 &= 0 && \text{elsewhere}
 \end{aligned}$$

- a) (15 points) Find the conditional probability density for  $x$  given  $y$ ,  $p(x|y)$ . Make a careful sketch of the result for the case  $y = L/2$ . Are  $x$  and  $y$  statistically independent random variables? Explain why or why not.
- b) (15 points) [Note: you do not need the results of a) to do this part.] Find the probability density for the function  $M \equiv \text{Max}(x, y)$  which takes on the value of the larger of the two quantities  $x$  and  $y$ . Sketch the result.

**Problem 2** (30 points) A Real Gas



A theoretical model for a certain real (non-ideal) gas gives the following expressions for the internal energy and the pressure.  $a$  and  $b$  are constant parameters which, for simplicity, include the dependence of  $U$  and  $P$  on the total number of atoms.

$$U(T, V) = aV^{-2/3} + bV^{2/3}T^2$$

$$P(T, V) = (2/3)aV^{-5/3} + (2/3)bV^{-1/3}T^2$$

Find an expression  $V = V(T, T_0, V_0)$  for the adiabatic path that passes through the point  $(T_0, V_0)$  in the  $V, T$  plane.

**Problem 3** (40 points) Ultra-relativistic Gas in One Dimension

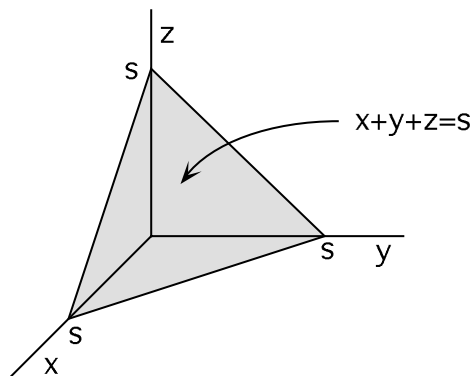
The microscopic state of each of the  $N$  identical atoms in a classical, weakly interacting, ultra-relativistic one dimensional gas can be described by three numbers: the atom's location  $x$  ( $0 \leq x \leq L$ ), the magnitude of its momentum  $p$  ( $0 \leq p \leq \infty$ ), and the sign of the momentum  $s$  ( $s = +1$  or  $-1$ ). The energy associated with an individual atom is  $\epsilon = cp$  where  $c$  is the velocity of light, and the total energy of the system is then

$$E = \sum_{i=1}^N \epsilon_i = c \sum_{i=1}^N p_i$$

Use the microcanonical ensemble with a total energy between  $E$  and  $E + \Delta$  where  $\Delta \ll E$  to find the properties of this gas.

- (16 points) Find the volume of the accessible region in phase space,  $\Omega(E, L, N)$ . Use the constant  $\hbar$  which has the units of length times momentum to render  $\Omega$  dimensionless, and make any adjustment necessary to assure that the Gibbs paradox is avoided. [You may want to make use of the mathematical result at the bottom of this page.]
- (8 points) Find the energy relation,  $E(T, L, N)$ . Note that the term  $\ln(N\Delta/E)$  can be neglected compared to other terms when computing the entropy of the gas.
- (8 points) Find the tension  $\mathcal{F}(T, L, N)$  in the gas. Note that  $-\mathcal{F}$  can be viewed as the analogue of the pressure in the one-dimensional gas, that is, a negative value of  $\mathcal{F}$  indicates that the gas is pushing out against its walls.
- (8 points) Make use of the calculations you have already done above to find the equation of an adiabatic path  $L = L(T, T_0, L_0)$  going through the point  $(T_0, L_0)$  in the  $T, L$  plane.

The following mathematical fact may be useful. The volume of a right angled pyramid of side  $S$  in 3 dimensions is  $(1/6)S^3$ . The volume of a right angled pyramid of side  $S$  in  $d$  dimensions is  $(1/d!)S^d$ .



## PARTIAL DERIVATIVE RELATIONSHIPS

Let  $x, y, z$  be quantities satisfying a functional relation  $f(x, y, z) = 0$ . Let  $w$  be a function of any two of  $x, y, z$ . Then

$$\begin{aligned}\left(\frac{\partial x}{\partial y}\right)_w \left(\frac{\partial y}{\partial z}\right)_w &= \left(\frac{\partial x}{\partial z}\right)_w \\ \left(\frac{\partial x}{\partial y}\right)_z &= \frac{1}{\left(\frac{\partial y}{\partial x}\right)_z} \\ \left(\frac{\partial x}{\partial y}\right)_z \left(\frac{\partial y}{\partial z}\right)_x \left(\frac{\partial z}{\partial x}\right)_y &= -1\end{aligned}$$

## COMBINATORIAL FACTS

There are  $K!$  different orderings of  $K$  objects. The number of ways of choosing  $L$  objects from a set of  $K$  objects is

$$\frac{K!}{(K-L)!}$$

if the order in which they are chosen matters, and

$$\frac{K!}{L!(K-L)!}$$

if order does not matter.

## STERLING'S APPROXIMATION

When  $K \gg 1$

$$\ln K! \approx K \ln K - K \quad \text{or} \quad K! \approx (K/e)^K$$

## DERIVATIVE OF A LOG

$$\frac{d}{dx} \ln u(x) = \frac{1}{u(x)} \frac{du(x)}{dx}$$

## VOLUME OF AN $\alpha$ DIMENSIONAL SPHERE OF RADIUS $R$

$$\frac{\pi^{\alpha/2}}{(\alpha/2)!} R^\alpha$$

## LIMITS

$$\lim_{n \rightarrow \infty} \frac{\ln n}{n} = 0$$

$$\lim_{n \rightarrow \infty} \sqrt[n]{n} = 1$$

$$\lim_{n \rightarrow \infty} x^{1/n} = 1 \quad (x > 0)$$

$$\lim_{n \rightarrow \infty} x^n = 0 \quad (|x| < 1)$$

$$\lim_{n \rightarrow \infty} \left(1 + \frac{x}{n}\right)^n = e^x \quad (\text{any } x)$$

$$\lim_{n \rightarrow \infty} \frac{x^n}{n!} = 0 \quad (\text{any } x)$$

## WORK IN SIMPLE SYSTEMS

System	Intensive quantity	Extensive quantity	Work
Hydrostatic system	$P$	$V$	$-PdV$
Wire	$\mathcal{F}$	$L$	$\mathcal{F}dL$
Surface	$\mathcal{S}$	$A$	$\mathcal{S}dA$
Reversible cell	$E$	$Z$	$E dZ$
Dielectric material	$\mathcal{E}$	$\mathcal{P}$	$\mathcal{E}d\mathcal{P}$
Magnetic material	$H$	$M$	$HdM$

## INTEGRALS

$$\int e^{ax} dx = \frac{e^{ax}}{a}$$

$$\int x e^{ax} dx = \frac{e^{ax}}{a^2}(ax - 1)$$

$$\int x^2 e^{ax} dx = \frac{e^{ax}}{a^3}(a^2x^2 - 2ax + 2)$$

$$\int \frac{dx}{1 + e^x} = \ln \left[ \frac{e^x}{1 + e^x} \right]$$

## DEFINITE INTEGRALS

For integer  $n$  and  $m$

$$\int_0^{\infty} x^n e^{-x} dx = n!$$

$$\int_0^{\infty} \frac{e^{-x}}{\sqrt{x}} dx = \sqrt{\pi}$$

$$(2\pi\sigma^2)^{-1/2} \int_{-\infty}^{\infty} x^{2n} e^{-x^2/2\sigma^2} dx = 1 \cdot 3 \cdot 5 \cdots (2n - 1) \sigma^n$$

$$\int_0^{\infty} x e^{-x^2} dx = \frac{1}{2}$$

$$\int_0^1 x^m (1 - x)^n dx = \frac{n!m!}{(m + n + 1)!}$$

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8.044 Statistical Physics I  
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